NSN 5961-00-023-4116

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-023-4116 **Inclosure Material:** Metal **Overall Length:** 0.410 inches **Overall Diameter:** 1.325 inches **Mounting Facility Quantity: Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Criticality Code Justification:** Feat **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 24.0 regulator voltage **Current Rating Per Characteristic:** 520.00 milliamperes repetitive peak forward current **Power Rating Per Characteristic:** 50.0 watts total power dissipation **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius case **Special Features:** Item must comply w/rqmt of desc production standard no. L00797 **Terminal Type And Quantity:** 2 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig:

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